

HER101S THRU HER108S



1.0 AMP HIGH EFFICIENCY RECTIFIERS



FEATURES

- * Low forward voltage drop
- * High current capability
- * High reliability
- * High surge current capability
- * High speed switching

MECHANICAL DATA

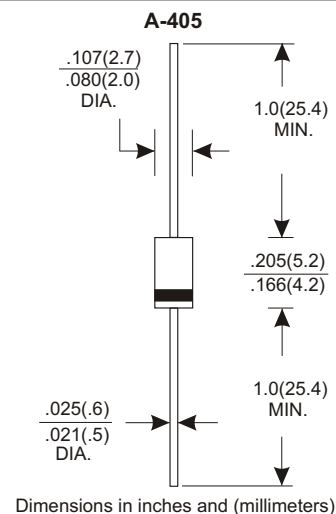
- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Lead: Axial leads, solderable per MIL-STD-202, method 208 guaranteed
- * Polarity: Color band denotes cathode end
- * Mounting position: Any

VOLTAGE RANGE

50 to 1000 Volts

CURRENT

1.0 Ampere



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

TYPE NUMBER	HER 101S	HER 102S	HER 103S	HER 104S	HER 105S	HER 106S	HER 107S	HER 108S	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	200	300	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length at Ta=55°C	1.0								A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	30								A
Maximum Instantaneous Forward Voltage at 1.0A	1.0			1.3		1.85			V
Maximum DC Reverse Current Ta=25°C	5.0								µA
at Rated DC Blocking Voltage Ta=100°C	100								µA
Maximum Reverse Recovery Time (Note 1)	50					75			nS
Typical Junction Capacitance (Note 2)	20					15			pF
Operating Temperature Range Tj	-65 — +150								°C
Storage Temperature Range Tstg	-65 — +150								°C

NOTES:

1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

RATING AND CHARACTERISTIC CURVES (HER101S THRU HER108S)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

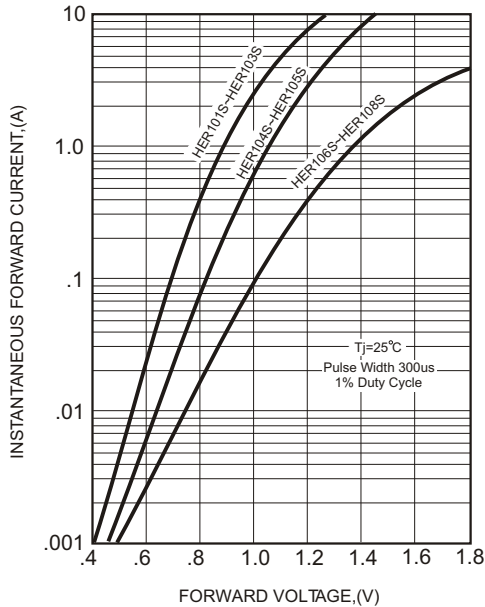


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

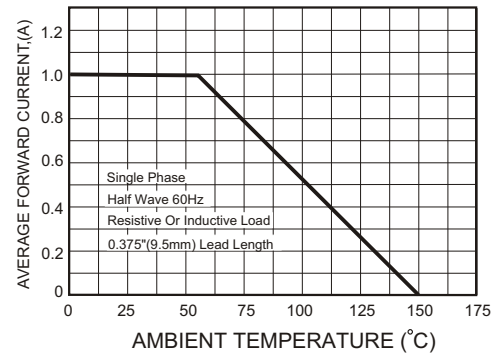


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

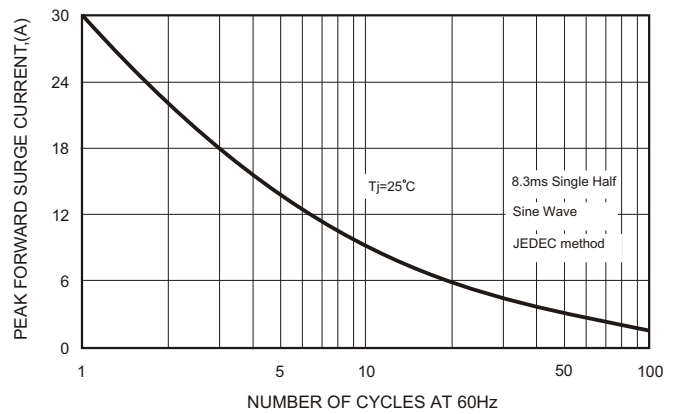
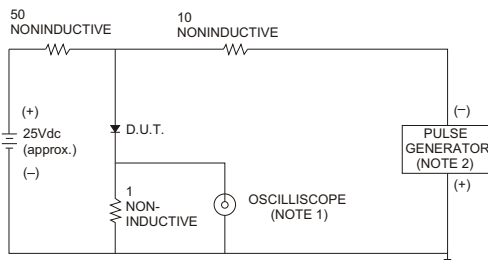


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm, 22pF.
2. Rise Time= 10ns max., Source Impedance= 50 ohms.

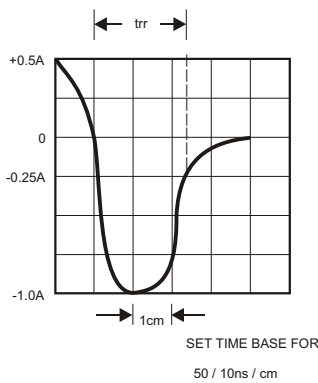


FIG.5-TYPICAL JUNCTION CAPACITANCE

